## NSN 5961-00-824-3777

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**Fiig:** A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-824-3777 **Inclosure Material:** Metal **Overall Length:** Between 0.250 inches and 0.450 inches Overall Diameter: 0.875 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: 60.0 collector to base voltage/static/emitter open and 35.0 collector to emitter voltage/static/base open and 45.0 collector to emitter voltage, dc with base short-circuited to emitter and 30.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 2.00 amperes source cutoff current and 7.00 amperes source cutoff current **Power Rating Per Characteristic:** 85.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 110.0 degrees celsius case **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No